

SMD Type Diodes

SCHOTTKY DIODE
SD104AWS

Features

- Low turn-on voltage
- Low Capacitance
- Ultrafast switching
- Microminiature plastic package
- Single, double, and ring balanced mixer in narrow band receivers up to 1 GHz
- Detectors and fast switching up to 1 GHz
- Phase detectors
- Suitable for trdios, TV, CTV, and hyper band tuners

Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Value	Unit
Continuous Reverse Voltage	V _R	20	V
Forward Current	I _F	30	mA
Power Dissipation T _c = 25 °C	P _{tot}	150 ⁽¹⁾	mW
Thermal Resistance Junction to Ambient Air	R _{θJA}	650 ⁽¹⁾	°C/W
Junction Temperature	T _J	125	°C
Storage Temperature Range	T _S	-55 to +150	°C

Note:

1. Valid provided that electrodes are kept at ambient temperature

Electrical Characteristics Ta = 25°C

Characteristic	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Breakdown Voltage (Note 2)	V _R	I _R = 10 μA	20			V
Leakage Current	I _R	V _R = 15V			500	V
Forward Voltage Drop	V _F	I _F = 0.1 mA			350	mV
		I _F = 1.0 mA			450	
		I _F = 10 mA			600	
Diodes Capacitance	C _D	V _R = 0 V, f = 1 MHz			0.8	pF

